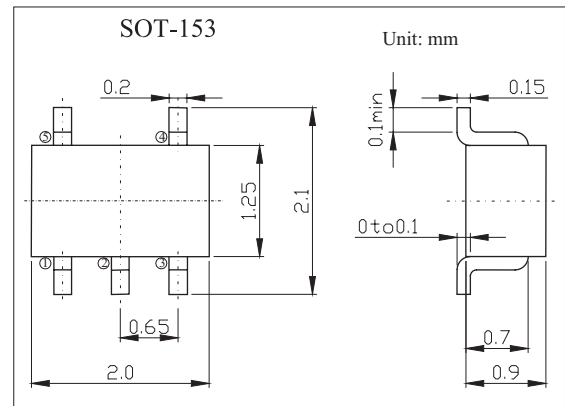
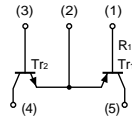


## Emitter Common (Dual Transistors) FMY1A

### ■ Features

- PNP and NPN transistors have common emitters.
- Mounting cost and area can be cut in half.



### ■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating		Unit
		Tr1	Tr2	
Collector-base voltage	$V_{CBO}$	-60	60	V
Collector-emitter voltage	$V_{CEO}$	-50	50	V
Emitter-base voltage	$V_{EBO}$	-6	7	V
Collector current	$I_C$	-150	150	mA
Power dissipation(Total)	$P_D$	300		mW
Operating and Storage and Temperature Range	$T_j, T_{STG}$	-55 to +150		$^\circ\text{C}$

## FMY1A

### ■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Transistor Tr1(PNP)						
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = -50 μA, I <sub>E</sub> = 0	-60			V
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = -1 mA, I <sub>B</sub> = 0	-50			V
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>C</sub> = -50 μA, I <sub>C</sub> = 0	-6			V
Collector cutoff current	I <sub>CBO</sub>	V <sub>CB</sub> = -60V, I <sub>E</sub> = 0			-100	nA
Emitter cutoff current	I <sub>EBO</sub>	V <sub>EB</sub> = -6V, I <sub>C</sub> = 0			-100	nA
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> = -6V, I <sub>C</sub> = -1mA	120		560	
collector-emitter saturation voltage *	V <sub>CE(sat)</sub>	I <sub>C</sub> = -50 mA; I <sub>B</sub> = -5 mA			-0.5	V
Transition frequency	f <sub>T</sub>	I <sub>C</sub> = -2 mA; V <sub>CE</sub> = -12 V; f = 100 MHz		140		MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = -12V, I <sub>E</sub> = 0A, f = 1MHz			5	pF
Transistor Tr2(NPN)						
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = 50 μA, I <sub>E</sub> = 0	60			V
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = 1 mA, I <sub>B</sub> = 0	50			V
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>C</sub> = 50 μA, I <sub>C</sub> = 0	7			V
Collector cutoff current	I <sub>CBO</sub>	V <sub>CB</sub> = 60V, I <sub>E</sub> = 0			100	nA
Emitter cutoff current	I <sub>EBO</sub>	V <sub>EB</sub> = 7V, I <sub>C</sub> = 0			100	nA
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> = 6V, I <sub>C</sub> = 1mA	120		560	
collector-emitter saturation voltage *	V <sub>CE(sat)</sub>	I <sub>C</sub> = 50 mA; I <sub>B</sub> = 5 mA			0.4	V
Transition frequency	f <sub>T</sub>	I <sub>C</sub> = 2 mA; V <sub>CE</sub> = 12 V; f = 100 MHz		180		MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 12V, I <sub>E</sub> = 0A, f = 1MHz			3.5	pF

\* pulse test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%.

### ■ Marking

Marking	Y1
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# FMY1A

## Typical Characteristics

Tr1 (PNP)

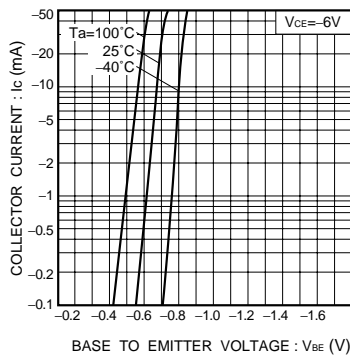


Fig.1 Grounded emitter propagation characteristics

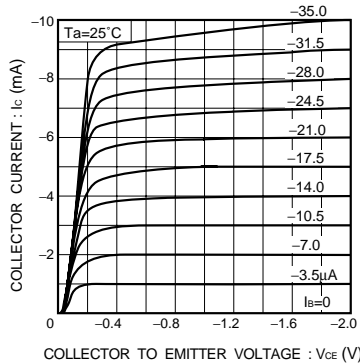


Fig.2 Grounded emitter output characteristics ( 1 )

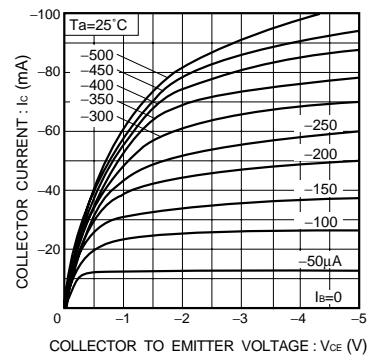


Fig.3 Grounded emitter output characteristics ( 2 )

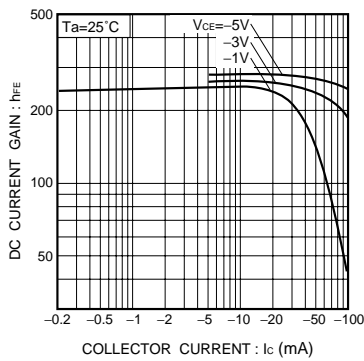


Fig.4 DC current gain vs. collector current ( 1 )

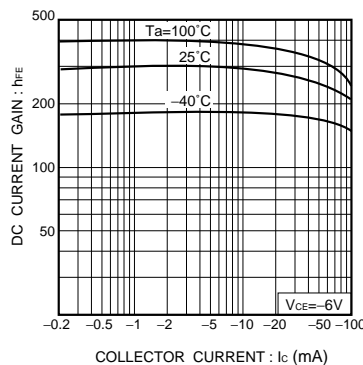


Fig.5 DC current gain vs. collector current ( 2 )

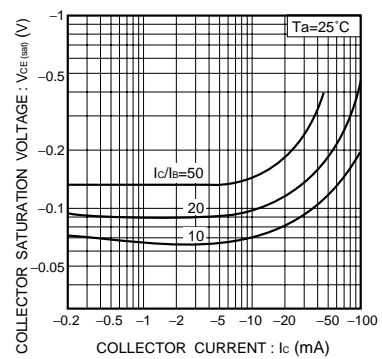


Fig.6 Collector-emitter saturation voltage vs. collector current ( 1 )

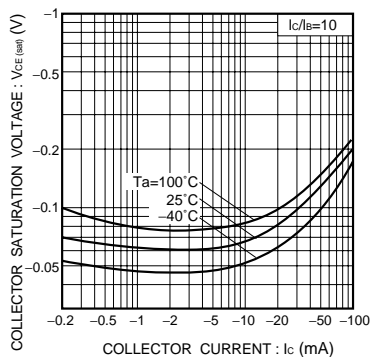


Fig.7 Collector-emitter saturation voltage vs. collector current ( 2 )

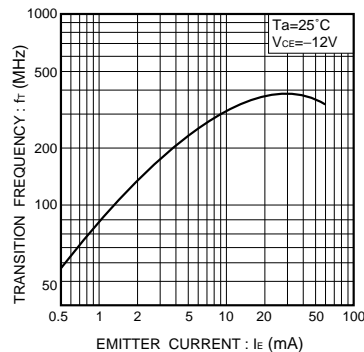


Fig.8 Gain bandwidth product vs. emitter current

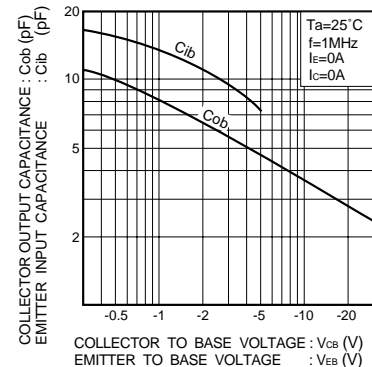


Fig.9 Collector output capacitance vs. collector-base voltage  
Emitter input capacitance vs. emitter-base voltage

# FMY1A

■ Typical Characteristics

Tr<sub>2</sub> (NPN)

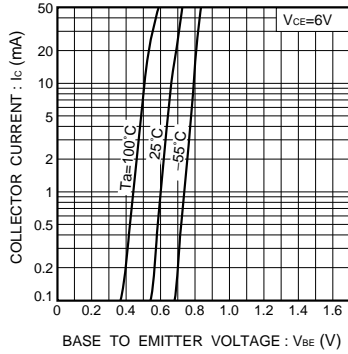


Fig.10 Grounded emitter propagation characteristics

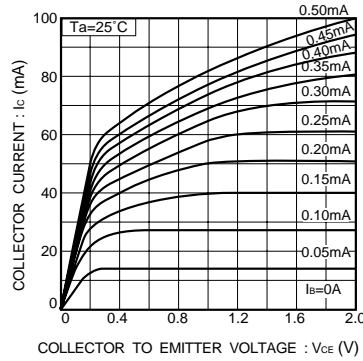


Fig.11 Grounded emitter output characteristics ( 1 )

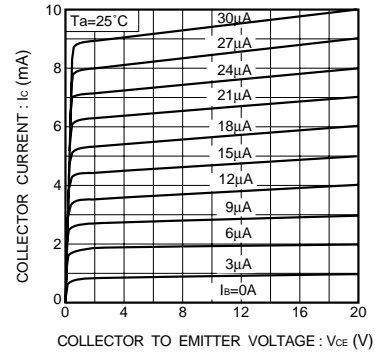


Fig.12 Grounded emitter output characteristics ( 2 )

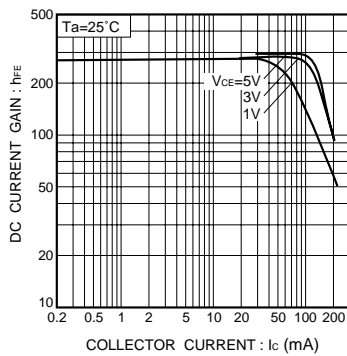


Fig.13 DC current gain vs. collector current ( 1 )

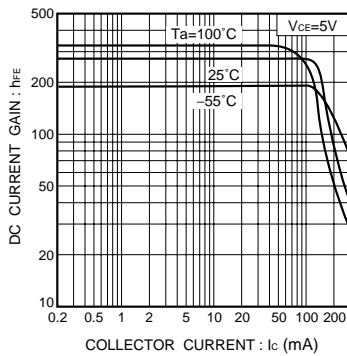


Fig.14 DC current gain vs. collector current ( 2 )

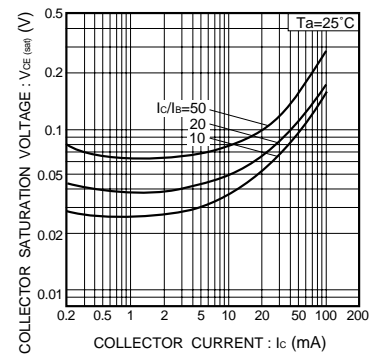


Fig.15 Collector-emitter saturation voltage vs. collector current ( 1 )

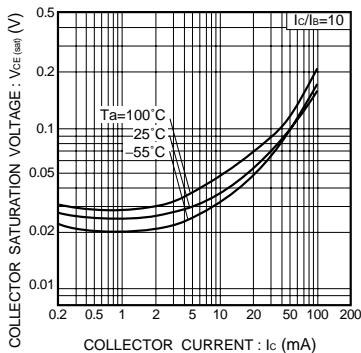


Fig.16 Collector-emitter saturation voltage vs. collector current ( 2 )

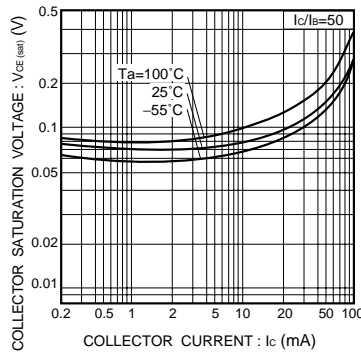


Fig.17 Collector-emitter saturation voltage vs. collector current ( 3 )

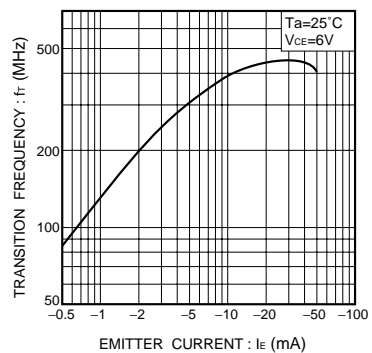


Fig.18 Gain bandwidth product vs. emitter current

# FMY1A

■ Typical Characteristics

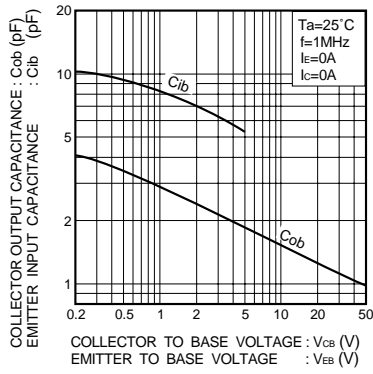


Fig.19 Collector output capacitance vs. collector-base voltage  
Emitter input capacitance vs. emitter-base voltage

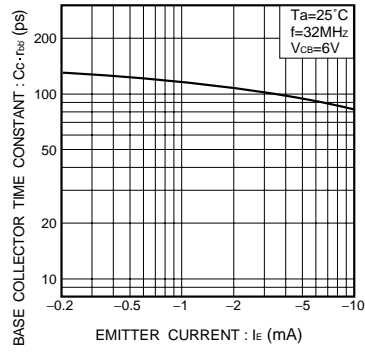


Fig.20 Base-collector time constant vs. emitter current